

Single-chip Type with Built-in FET Switching Regulator Series

Step-down Switching regulators with Built-in Power MOSFET

BU9000xGWZ series

General Description

The BU9000xGWZ are a high efficiency 6MHz synchronous step-down switching regulator with ultra low current PFM mode.

It provides up to 1.0A load current and an input voltage range from 3.0V to 5.5V, optimized for battery powered portable applications.

BU9000xGWZ has a mode control pin that allows the user to select Forced PWM (Pulse Width Modulation) mode or PFM (Pulse Frequency Modulation) and PWM auto change mode utilized power save operation at light load current.

Features

- Fast transient response
- Automatic PFM/PWM operation
- Forced PWM operation
- Internal Soft Start
- Under voltage lockout
- Over current protection
- Thermal shutdown

●Lineup

Applications

Smart phones, Cell phones, Portable applications, Micro DC/DC modules, and USB accessories

Package(s)

UCSP35L1

W(Typ.) x D(Typ.) x H(Max.) 1.30mm x 0.90mm x 0.40mm

Typical Application Circuit(s)



Figure 1. Typical Application Circuit(s)

Part No	Output		Switching froguonov	Operating mode		
Fait NO.	voltage	input voltage	Switching nequency	MODE=L	MODE=H	
BU90002GWZ	3.30V	4.0V to 5.5V	5.4MHz to 6.6MHz			
BU90003GWZ	1.20V	2.3V to 5.5V	3.6MHz to 4.4MHz	3.6MHz to 4.4MHz Automatic PEM/PW/M		
BU90004GWZ	1.80V	2.3V to 5.5V	4.8MHz to 6.0MHz			
BU90005GWZ	2.50V	2.3V to 5.5V	5.4MHz to 6.6MHz	Forced PFM	Earoad D\//M	
BU90006GWZ	3.00V	2.3V to 5.5V	5.4MHz to 6.6MHz			
BU90007GWZ	1.25V	2.3V to 5.5V	3.6MHz to 4.4MHz	Automatic		
BU90008GWZ	1.00V	2.3V to 5.5V	3.2MHz to 4.0MHz	PFM/PWM		
BU90009GWZ	1.30V	2.3V to 5.5V	3.8MHz to 4.8MHz			

Pin Configuration(s)





Figure 2. Pin Configuration(s)

Pin Description(s)

Pin No.	Symbol	Function
A1	VIN	Power supply input pin
A2	EN	Enable pin
A3	GND	GND pin
B1	MODE	Forced PWM mode pin
B2	LX	Inductor connection pin
B3	FB	Feedback voltage input pin

OProduct structure : Silicon monolithic integrated circuit OThis product is not designed protection against radioactive rays

Block Diagram(s)



Figure 3. Block Diagram(s)

Description of Block(s)

The BU9000xGWZ are a synchronous step-down DC/DC converter that achieves fast transient response from light load to heavy load by hysteretic PWM control system and current constant PFM control system.

OPWM control

BU9000xGWZ operates by hysteretic PWM control. This scheme ensures fast switching, high efficiency, and fast transient response.

When the output voltage is below the VREF voltage, the error comparator output is low to high and turning on P-channel MOSFET until above the VREF voltage and minimum on time.

OPFM control

At light load the regulator and MODE=low, the regulator operates with reduced switching frequency and improves the efficiency.During PFM operation, the output voltage slightly higher than typical output voltage.





Description of operations

1) Shutdown

If the EN input pin set to low (<0.4V), all circuit are shut down and the regulator is standby mode. Do not leave the EN pin floating.

2) Soft start function

The regulator has a soft start circuit that reduces in-rush current at start-up. Typical start up times with a 4.7uF output capacitor is 120usec.

3) Current limit

The BU9000xGWZ has a current limit circuit that protects itself and external components during overload condition.

4) UVLO

The BU9000xGWZ has a Under Voltage Lock Out circuit that turn off device when VIN>2.05V(typ.)

5) FORCED PWM MODE

Setting MODE pin high (>1.4V) places the regulator in forced PWM. This control provides noise reduction and output stability. Do not leave the MODE pin floating.

6) FORCED PFM MODE (BU90005GWZ)

Setting MODE pin low (<0.4V) places the regulator in forced PFM. It is effective in light load mode.

7) TSD

The BU9000xGWZ has a thermal shutdown feature to protect the device if the junction temperature exceeds 150°C.In thermal shutdown, the DRIVER is disabled.

This circuit is only to cut off the IC from thermal runaway, and has not been design to protect or guarantee the IC. Therefore, the user should not plan to activate this circuit with continued operation in mind.

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Unit
Maximum input power supply voltage	VIN	7	V
Maximum voltage at EN, FB, LX, MODE	VEN, VFB, VLX, VMODE	7	V
Power dissipation	Pd	0.39(*1)	W
Operating temperature range	Topr	-40 to +85	S
Storage temperature range	Tstg	-55 to +125	S
Junction temperature	Tjmax	+125	°C

(*1) When mounted on the specified PCB (55mm x 63mm), Deducted by 3.9m W/c when used over Ta=25c

Recommended Operating Rating(s)

Parameter	Symbol	Rating			Lloit	Soriao
		Min.	Тур.	Max.	Unit	361136
Input voltage	VIN	4.0	-	5.5	V	BU90002GWZ
		2.3	-	5.5		BU90003~BU90009GWZ

● Electrical Characteristic(s) (unless otherwise specified VIN=3.6V, Ta=25°C)

Itom		Cumphiel		Rating		Linit	Condition
		Symbol	Min.	Тур.	Max.	Unit	Condition
[Switching regulator]							
Output voltage accuracy			-2	-	+2		MODE:H(PWM Operation)
		VOUTA	-2	-	+3	%	MODE:L(PFM Operation)
		loutMAX1	-	-	1.0	Δ	$3.0V \leq VIN \leq 5.5V$
		IoutMAX2	-	-	0.8	A	$2.7V \leq VIN < 3.0V$
Maximum load c	urrent	loutMAX3	-	_	0.6	A	$2.3V \leq VIN \leq 2.7V$
					0.1	^	MODE:L(PFM Operation)
		IOULIWAA4	-	-	0.1	A	(BU90005GWZ,)
[Soft start]		1					
Soft start time		Tss	65	120	240	usec	(BU90002GWZ, BU90003GWZ, BU90004GWZ, BU90005GWZ, BU90006GWZ, BU90007GWZ, BU90009GWZ)
			55	110	220	usec	(BU90008GWZ)
[Frequency cont	irol]		5.4	6.0	6.6	MHz	No load, MODE:H (BU90002GWZ,BU90005GWZ, BU90006GWZ)
			4.8	5.4	6.0	MHz	NO IOAD, MODE:H (BU90004GWZ)
Switching freque	ency	fosc	3.6	4.0	4.4	MHz	No load, MODE:H
			3.0	36	4.0	Mu-	No load, MODE:H
			3.2	3.0	4.0		(BU90008GWZ)
			3.8	4.3	4.8	MHz	(BU90009GWZ)
[Driver]							
		RonP1	-	250	400	mOhm	VIN=5.0V
FUIFET OITTESIS	ance	RonP2		300	450	mOhm	VIN=3.6V
NchEET on resis	tance	RonN1	-	220	350	mOhm	VIN=5.0V
		RonN2		250	380	mOhm	VIN=3.6V
[Control]	Т	1			1		
EN pin control	Operation	VENH	1.4	-	VIN	V	
voltage	Non Operation	VENL	0	-	0.4	V	
MODE pin	Operation	VMODEH	1.4	-	VIN	V	Forced PWM
control voltage	Non Operation	VMODEL	0	-	0.4	V	Automatic PFM/PWM (BU90005GWZ : Forced PFM)
[UVLO]	I	1					, ,
Protect threshold	Protect threshold voltage		1 95	2.05	2 15	V	
	Voltage	Uvbr	F.0	100	450	w\/	
		Ovity	50	100	150	IIIV	
		,					PMOS ourront dataat
Current limit thre	shold	ILIMIT	1.5	1.7	1.9	A	Open loop
[Output discharge]						•	
Output discharge	e resistance	DRES	15	30	60	Ohm	EN=0V, FB=0.5V
[Circuit current]							
Operating quiescent current		IINS1	-	45	65	uA	No load, EN:H, MODE:L, VOUT=3.6V forced Not switching (BU90003GWZ, BU90004GWZ, BU90005GWZ, BU90007GWZ, BU90008GWZ, BU90009GWZ)
		IINS2	-	55	80	uA	No load, EN:H, MODE:L, VOUT=3.6V forced Not switching (BU90002GWZ,BU90006GWZ)
		IQ1	-	5.2	-	mA	No load, EN:H, MODE:H, PWM operation L:LQM21MPN1R0NG0 (BU90003GWZ)
		IQ2	-	5.6	-	mA	No load, EN:H, MODE:H, PWM operation L:LQM21MPN1R0NG0 (BU90004GWZ)
Shutdown currer	nt	SHD	-	0	1	uA	EN=0V

•Electrical Characteristic curves (Reference data) BU90002GWZ (3.3V OUTPUT)

Parts

L:LQM21MPN1R0NG0 (2.0mm × 1.6mm × 1.0mm Murata) COUT:GRM155R60J475M(1.0mm × 0.5mm × 0.5mm Murata)





Figure 8. Load transient response 50mA to 350mA tr=tf=100ns, MODE : Low





•Electrical characteristic curves (Reference data) BU90003GWZ (1.2V OUTPUT)



Figure 19. Load transient response 5mA to 200mA tr=tf=100ns, MODE : Low

Figure 20. Load transient response 50mA to 350mA tr=tf=100ns, MODE : Low



Figure 21. Load transient response 400mA to 1000mA tr=tf=100ns, MODE : Low





Figure 23. Fig.23 PWM mode Operation lout=100mA

Figure 24. Mode Change Response MODE : High to Low



•Electrical characteristic curves (Reference data) BU90004GWZ (1.80V OUTPUT)



Figure 30. Load transient response 5mA to 200mA tr=tf=100ns, Mode : Low

Figure 31. Load transient response 50mA to 350mA tr=tf=100ns, Mode :Low



M 80.0ns 2.5GS/s A Ch1 \ 3.72V IT 160ps/pt

Figure 35. Mode Change Response MODE : High to Low

Ch1 Ch3 2.0Y 20.0mY % Bw 200mA/div

Ch1 Ch3 5.0Y 50.0mV % Bw

Ch4

200mA Ω

M 4.0µs 125MS/s A Ch1 \ 2.2V 8.0ns/pt



• Electrical characteristic curves (Reference data) BU90005GWZ (2.50V OUTPUT)



Figure 41. Load transient response 5mA to 100mA tr=tf=100ns, MODE : Low

Figure 42. Load transient response 50mA to 350mA tr=tf=100ns, MODE : High



Figure 43. Load transient response 200mA to 600mA tr=tf=100ns, MODE : High

Figure 44. PFM mode Operation lout=50mA



Figure 45. PWM mode Operation Iout=100mA

Figure 46. Mode Change Response MODE : High to Low





Figure 49. Efficiency vs Load current PWM mode

•Electrical characteristic curves (Reference data) BU90008GWZ (1.000V OUTPUT)



Figure 52. Load transient response 5mA to 100mA tr=tf=100ns, MODE : Low

Figure 53. Load transient response 50mA to 350mA tr=tf=100ns, MODE : High



Figure 56. PWM mode Operation Iout=100mA

Figure 57. Mode Change Response MODE : High to Low



Figure 60. Efficiency vs Load current PWM mode

Load current[mA]

•Electrical characteristic curves (Reference data) BU90009GWZ (1.300V OUTPUT)



Figure 63. Load transient response 5mA to 50mA tr=tf=100ns, MODE : Low

Figure 64. Load transient response 50mA to 350mA tr=tf=100ns, MODE : Low



Figure 67. PWM mode Operation lout=100mA

Figure 68. Mode Change Response MODE : High to Low



Figure 71. Load regulation PWM/PFM Auto mode

•PC Board layout

The suggested PCB layout for the BU9000xGWZ are shown in Figure. The following guidelines should be used to ensure a proper layout.

1) The input capacitor CIN should be connect as closely possible to VIN pin and GND pin.

2) From the output voltage to the FB pin line should be as separate as possible.

3) COUT and L should be connected as closely as possible. The connection of L to the LX pin should be as short as possible.



Figure 72. PCB layout

External parts selection

Inductor selection

The inductance significantly depends on output ripple current. As shown by following equation, the ripple current decreases as the inductor and/or switching frequency increase.

$$\Delta I_{L} = \frac{(VIN-VOUT) \times VOUT}{L \times VIN \times f}$$

f: switching frequency L: inductance ΔI_L : inductor current ripple

As a minimum requirement, the DC current rating of the inductor should be equal to the maximum load current plus half of the inductor current ripple as shown by the following equation.

$$I_{LPEAK} = I_{OUTMAX} + \frac{\Box I_L}{2}$$

1) Recommended inductor selection

• lout≦1A

LQM2MPN1R0NG0 (2.0mm×1.6mm×1.0mm Murata) MIPSZ2016D1R0FH (2.0mm×1.6mm×1.0mm FDK) DFE252012C1R0 (2.5mm×2.0mm×1.2mm TOKO)

∙ lout≦0.6A

LQM21PN1R0NGC (2.0mm×1.2mm×1.0mm Murata) MIPSZ2012D1R0 (2.0mm×1.2mm×1.0mm FDK) MIPSTZ1608D1R0 (1.6mm×0.8mm×0.8mm FDK) MLP2012H1R0M (2.0mm×1.2mm×1.0mm TDK) CKP2012N1R0N (2.0mm×1.2mm×1.0mm Taiyo Yuden)

- 2) Recommended input capacitor(CIN) selection GRM155R60J225M(1.0mm × 0.5mm × 0.5mm Murata) GRM155R60J475M(1.0mm × 0.5mm × 0.5mm Murata) GRM155R60G106M(1.0mm × 0.5mm × 0.5mm Murata)
- 3) Recommended output capacitor(COUT) selection GRM155R60J475M(1.0mm × 0.5mm × 0.5mm Murata) GRM155R60G106M(1.0mm × 0.5mm × 0.5mm Murata)

OCautions on the output capacitor selection

The BU9000xGWZ is designed to fixed soft-start time and operate with a maximum output capacitance of 10uF. If the capacitance connected to the output is larger than 10uF, an overshoot of the output voltage will be caused. It is possible to cause damage on the connected device.

●I/O equivalence circuit(s)



Caution of use

1) Absolute maximum ratings

An excess in the absolute maximum rating, such as supply voltage, temperature range of operating conditions, etc., can break down the devices, thus making impossible to identify breaking mode, such as a short circuit or an open circuit. If any over rated values will expect to exceed the absolute maximum ratings, consider adding circuit protection devices, such as fuses.

2) GND voltage

The potential of GND pin must be minimum potential in all condition. As an exception, the circuit design allows voltages up to -0.3 V to be applied to the IC pin.

3) Thermal design

Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions.

4) Inter-pin shorts and mounting errors

Use caution when positioning the IC for mounting on printed circuit boards. The IC may be damaged if there is any connection error or if pins are shorted together.

5) Actions in strong electromagnetic field

Use caution when using the IC in the presence of a strong electromagnetic field as doing so may cause the IC to malfunction.

6) Mutual impedance

Power supply and ground wiring should reflect consideration of the need to lower mutual impedance and minimize ripple as much as possible (by making wiring as short and thick as possible or rejecting ripple by incorporating inductance and capacitance).

7) Thermal shutdown Circuit (TSD Circuit)

This model IC has a built-in TSD circuit. This circuit is only to cut off the IC from thermal runaway, and has not been design to protect or guarantee the IC. Therefore, the user should not plan to activate this circuit with continued operation in mind.

8) Regarding input pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated.

P-N junctions are formed at the intersection of these P layers with the N layers of other elements, creating a parasitic diode or transistor. For example, as shown in the figures below, the relation between each potential is as follows:

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes can occur inevitable in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Accordingly, methods by which parasitic diodes operate, such as applying a voltage that is lower than the GND (P substrate) voltage to an input pin, should not be used.

9) Disturbance light

In a device where a portion of silicon is exposed to light such as in a WL-CSP, IC characteristics may be affected due to photoelectric effect. For this reason, it is recommended to come up with countermeasures that will prevent the chip from being exposed to light.

Status of this document

The Japanese version of this document is formal specification. A customer may use this translation version only for a reference to help reading the formal version.

If there are any differences in translation version of this document formal version takes priority

Ordering Information



Marking Diagram(s)(TOP VIEW)



Part Number Marking		
AB4		
AB6		
AB7		
AB8		
AB9		
ACM		
ADW		
ADV		

Physical Dimension, Tape and Reel Information



Revision History

Date	Revision	Changes
04.Jul.2012	001	New Release
16.Oct.2013	002	Page18 1) Recommended inductor selection MIPSZ2016D1R0FH, MIPSZ2012D1R0 added.
28.Oct.2013	003	Page4 Electrical Characteristic(s) Operating quiescent current IQ1(BU90003GWZ PWM operation), IQ2(BU90004GWZ PWM operation) added.
29.May.2014	004	Page19 I/O equivalence circuit added. Page20⇒Page22 Physical Dimension, Tape and Reel Information
8.Dec.2014	005	Page20 Caution of use 9) Disturbance light added.
15.May.2015	006	BU90008GWZ added. Page 2 Figure 3. Block Diagram(s) Range of the output capacitor capacity added. Page21 Cautions on the output capacitor selection added.
7.Jul.2015	007	BU90009GWZ added. Page 4 Output discharge resistance Correction of errors

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